

# 4A, 200V - 600V Surface Mount Ultrafast Power Rectifier

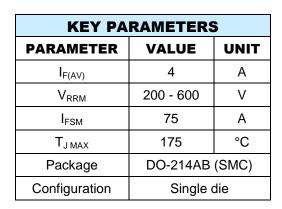
#### **FEATURES**

- Glass passivated junction
- Ideal for automated placement
- Built-in strain relief
- Ultrafast recovery time for high efficiency
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

- High frequency rectification
- Freewheeling application
- Switching mode converters and inverters in computer, automotive and telecommunication.

#### **MECHANICAL DATA**

- Case: DO-214AB (SMC)
- Molding compound meets UL 94V-0 flammability rating
- Part no. with suffix "H" means AEC-Q101 qualified
- Packing code with suffix "G" means green compound (halogen-free)
- Moisture sensitivity level: level 1, per J-STD-020
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.25 g (approximately)







**DO-214AB (SMC)** 

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER	SYMBOL	MUR420S	MUR440S	MUR460S	UNIT	
Marking code on the device		MUR420S	MUR440S	MUR460S		
Repetitive peak reverse voltage	$V_{RRM}$	200	400	600	V	
Reverse voltage, total rms value	$V_{R(RMS)}$	140	280	420	V	
Maximum DC blocking voltage	$V_{DC}$	200	400	600	V	
Forward current	I <sub>F(AV)</sub>	4		Α		
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	75			А	
Junction temperature	$T_J$	- 55 to +175		°C		
Storage temperature	T <sub>STG</sub>	- 55 to +175			°C	

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THERMAL PERFORMANCE					
PARAMETER	SYMBOL	TYP	UNIT		
Junction-to-ambient thermal resistance per diode	R <sub>eJA</sub>	45	°C/W		
Junction-to-case thermal resistance per diode	R <sub>eJC</sub>	8.5	°C/W		

ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	TYP.	MAX.	UNIT
<b>5</b>	MUR420S	I <sub>F</sub> = 4A, T <sub>J</sub> = 25°C	V <sub>F</sub>	1	0.875	V
	MUR440S MUR460S			-	1.250	V
Forward voltage per diode (1)	MUR420S		V <sub>F</sub>	-	0.710	V
	MUR440S MUR460S	$I_F = 4A, T_J = 150$ °C		-	1.050	V
Reverse current @ rated $V_R$	MUR420S	T <sub>J</sub> = 25°C	I <sub>R</sub>		5	μA
	MUR440S MUR460S			-	10	μA
per diode <sup>(2)</sup>	MUR420S		I <sub>R</sub>	-	150	μA
	MUR440S MUR460S	T <sub>J</sub> = 150°C		ı	250	μΑ
Junction capacitance		1 MHz, V <sub>R</sub> =4.0V	CJ	65	-	pF
Reverse recovery time	MUR420S	I <sub>F</sub> =0.5A , I <sub>R</sub> =1.0A I <sub>RR</sub> =0.25A	t <sub>rr</sub>	-	25	ns
	MUR440S MUR460S			-	50	ns

### Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms



ORDERING INFORMATION						
PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING	
		R7	R7		850 / 7" Plastic reel	
		R6		SMC	3,000 / 13" Paper reel	
MUR4xxS	l H	M6	G	SMC	3,000 / 13" Plastic reel	
(Note 1,2)		V7		Matrix SMC	850 / 7" Plastic reel	
		V6		Matrix SMC	3,000 / 13" Plastic reel	

### Note:

- 1. "xx" defines voltage from 50V (MUR42S) to 600V (MUR460S)
- 2. Only V6 and V7 are all green compound (halogen free)

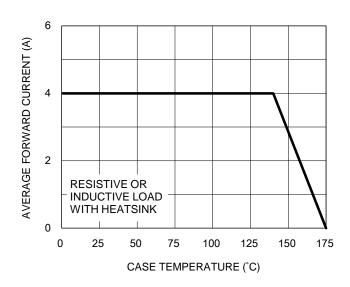
EXAMPLE					
EXAMPLE P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
MUR420SHR7G	MUR420S	Н	R7	G	AEC-Q101 qualified Green compound



### **CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25°C unless otherwise noted)

Fig.1 Forward Current Derating Curve



**Fig.2 Typical Junction Capacitance** 

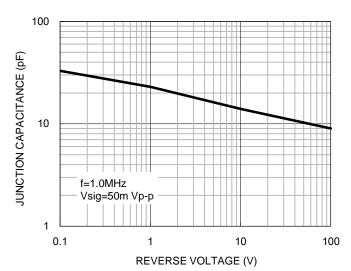


Fig.3 Typical Reverse Characteristics

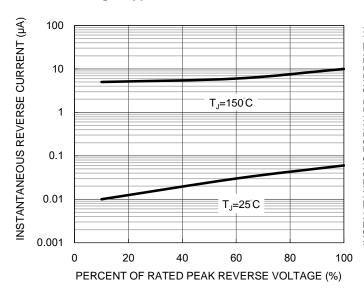
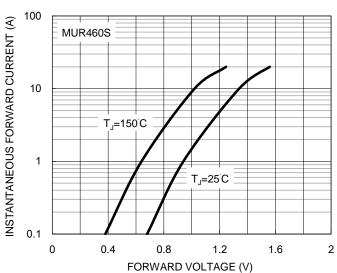


Fig.4 Typical Forward Characteristics



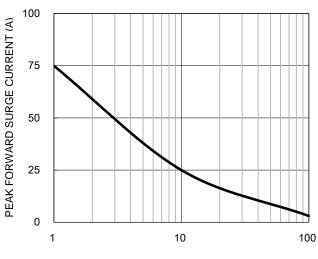
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### **CHARACTERISTICS CURVES**

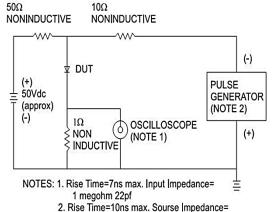
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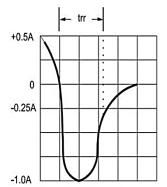
Fig.5 Maximum Non-repetitive Forward Surge Current



NUMBER OF CYCLES AT 60 Hz

Fig.6 Reverse Recovery Time Characteristic And Test Circuit Diagram



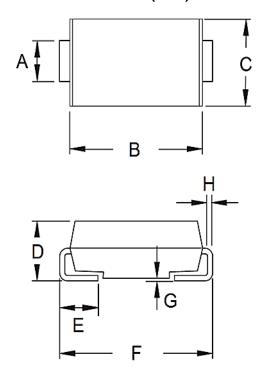


2. Rise Time=10ns max. Sourse Impedance= 50 ohms



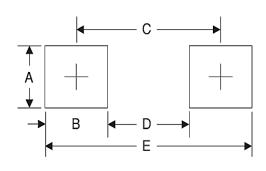
# **PACKAGE OUTLINE DIMENSIONS**

# DO-214AB (SMC)



Uni		(mm)	Unit (inch)	
DIM.	Min.	Max.	Min.	Max.
Α	2.90	3.20	0.114	0.126
В	6.60	7.11	0.260	0.280
С	5.59	6.22	0.220	0.245
D	2.00	2.62	0.079	0.103
Е	1.00	1.60	0.039	0.063
F	7.75	8.13	0.305	0.320
G	0.10	0.20	0.004	0.008
Н	0.15	0.31	0.006	0.012

# **SUGGESTED PAD LAYOUT**



Symbol	Unit (mm)	Unit (inch)
А	3.30	0.130
В	2.50	0.098
С	6.80	0.268
D	4.40	0.173
Е	9.40	0.370

### **MARKING DIAGRAM**

**Matrix SMC** 

**SMC** 





P/N =Marking Code G =Green Compound

YW =Date Code F =Factory Code



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